

# Digital transistors (built-in resistors)

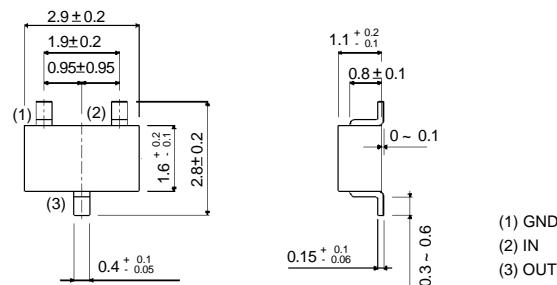
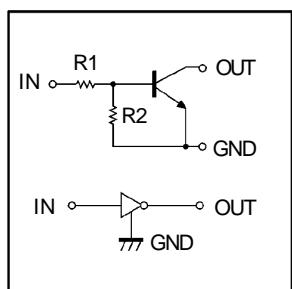
- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

- Structure

PNP digital transistor (Built-in resistors type)

- Equivalent circuit



EIAJ: SC—59

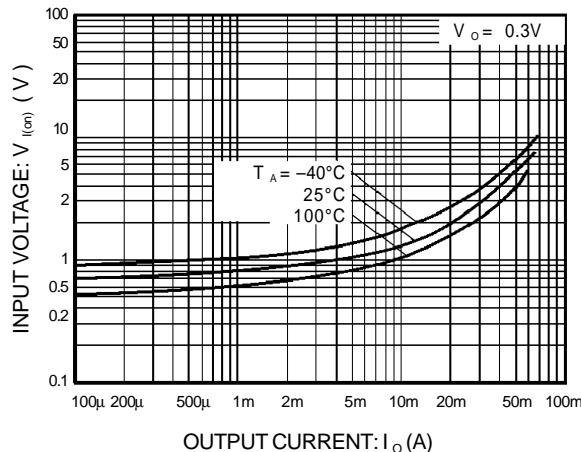
- Absolute maximum ratings( $T_a=25^\circ\text{C}$ )

Parameter	symbol	limits		unit
Supply voltage	$V_{cc}$	50		V
Input voltage	$V_{IN}$	-6~+40		V
Output current	$I_o$	70		mA
	$I_{C(\text{Max.})}$	100		
Power dissipation	$P_d$	200		mW
Junction temperature	$T_j$	150		°C
Storage temperature	$T_{stg}$	-55~+150		°C

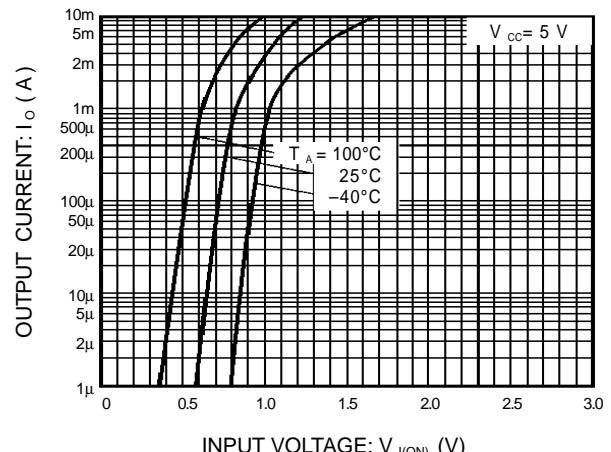
- Electrical characteristics( $T_a=25^\circ\text{C}$ )

Parameter	symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(\text{off})}$	—	—	0.3	V	$V_{cc}=5\text{V}, I_o=100\mu\text{A}$
	$V_{I(\text{on})}$	1.4	—	—		$V_o=0.3\text{V}, I_o=1\text{mA}$
Output Voltage	$V_{O(\text{on})}$	—	0.1	0.3	V	$I_o/I_i=5\text{mA}/0.25\text{mA}$
Input current	$I_i$	—	—	0.88	mA	$V_i=5\text{V}$
Output current	$I_{O(\text{off})}$	—	—	0.5	μA	$V_{cc}=50\text{V}, V_i=0\text{V}$
DC current gain	$G_i$	68	—	—	—	$V_o=5\text{V}, I_o=5\text{mA}$
Input resistance	$R_i$	7	10	13	KΩ	—
Resistance ratio	$R_2 / R_1$	3.7	4.7	5.7	—	—
Transition frequency	$f_T$	—	250	—	MHz	$V_{ce}=10\text{V}, I_E=-5\text{mA}, f=100\text{MHz}^*$

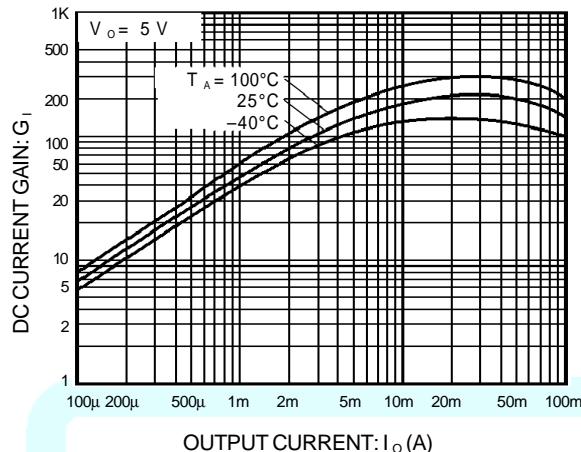
\*Transition frequency of the device

**ELECTRICAL CHARACTERISTIC CURVES**


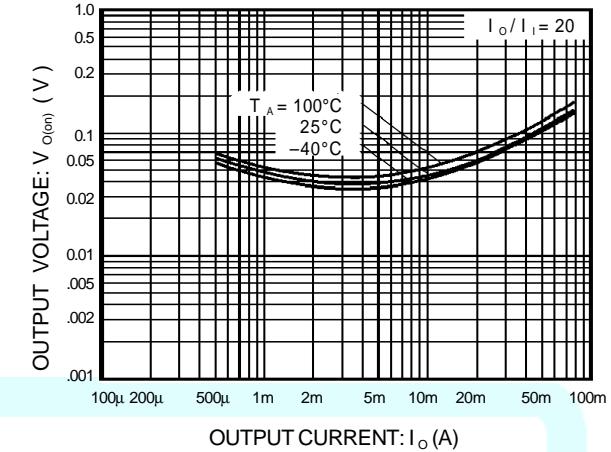
**Figure 1. Input voltage vs.output current  
(ON characteristics)**



**Figure 2. Output current vs.input voltage  
(OFF characteristics)**



**Figure 3. DC current gain vs.output current**



**Figure 4. Output voltage vs.output current**